

PMEG4002EB

0.2 A very low V_F MEGA Schottky barrier rectifier in SOD523 package

Rev. 01 — 12 July 2005

Product data sheet



1. Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD523 (SC-79) ultra small and flat lead Surface Mounted Device (SMD) plastic package.

1.2 Features

Forward current: 200 mA

Reverse voltage: 40 V

- Very low forward voltage
- Ultra small and flat lead SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Inverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1: Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		-	-	200	mA
V_R	reverse voltage		-	-	40	V
V _F	forward voltage	$I_F = 200 \text{ mA}$	<u>[1]</u> _	520	600	mV

[1] Pulse test: $t_0 \le 300 \,\mu\text{s}$; $\delta \le 0.02$.





2. Pinning information

Table 2: Pinning

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	. 84
2	anode	1 2	1 🔂 2
			sym001

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3: Ordering information

Type number	Package		
	Name	Description	Version
PMEG4002EB	SC-79	plastic surface mounted package; 2 leads	SOD523

4. Marking

Table 4: Marking codes

Type number	Marking code
PMEG4002EB	L9

5. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions	Min	Max	Unit
reverse voltage		-	40	V
forward current		-	200	mA
repetitive peak forward current	$t_p \leq 1 \text{ s; } \delta \leq 0.5$	-	300	mA
non-repetitive peak forward current	t _p = 8.3 ms half sine wave; JEDEC method	-	1	A
junction temperature		-	150	°C
ambient temperature		-65	+150	°C
storage temperature		-65	+150	°C
	reverse voltage forward current repetitive peak forward current non-repetitive peak forward current junction temperature ambient temperature	reverse voltage	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$

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6. Thermal characteristics

Table 6: Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2] _	-	450	K/W

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

7. Characteristics

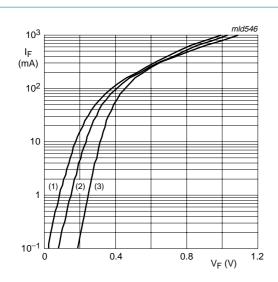
Table 7: Characteristics

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

		•				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 0.1 \text{ mA}$	-	190	220	mV
		I _F = 1 mA	-	250	290	mV
		I _F = 10 mA	-	320	360	mV
		I _F = 100 mA	-	440	500	mV
		$I_F = 200 \text{ mA}$	-	520	600	mV
I _R	reverse current	V _R = 25 V	<u>[1]</u> _	-	0.5	μΑ
C_{d}	diode capacitance	$V_R = 1 V; f = 1 MHz$	-	-	20	pF

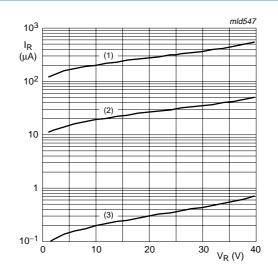
^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

^[2] For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and $I_{F(AV)}$ rating will be available on request.



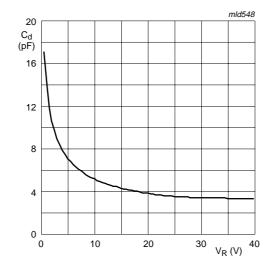
- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \,^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

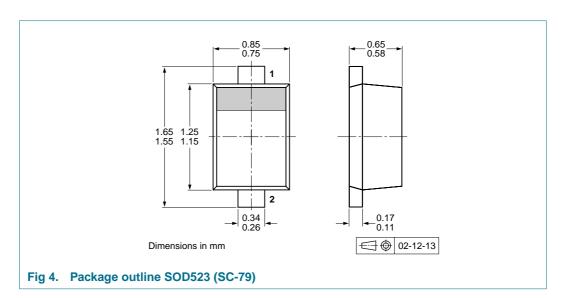
Fig 2. Reverse current as a function of reverse voltage; typical values



 T_{amb} = 25 °C; f = 1 MHz

Fig 3. Diode capacitance as a function of reverse voltage; typical values

8. Package outline



9. Packing information

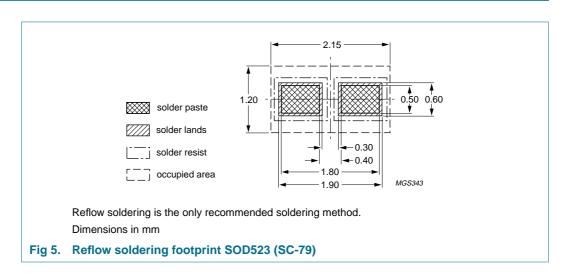
Table 8: Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing (quantity
			3000	10000
PMEG4002EB	SOD523	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see $\underline{\text{Section 16}}$.

10. Soldering



PMEG4002EB_1

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11. Revision history

Table 9: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
PMEG4002EB_1	20050712	Product data sheet	-	-	-

12. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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- [2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- [3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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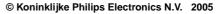
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17. Contents

1	Product profile
1.1	General description1
1.2	Features
1.3	Applications
1.4	Quick reference data
2	Pinning information
3	Ordering information
4	Marking 2
5	Limiting values
6	Thermal characteristics 3
7	Characteristics 3
8	Package outline
9	Packing information 5
10	Soldering 5
11	Revision history6
12	Data sheet status
13	Definitions 7
14	Disclaimers 7
15	Trademarks 7
16	Contact information



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